

ROHM Switching Regulator Solutions

Evaluation Board: Synchronous Buck Converter Integrated FET

BD9E151NUX-E2EVK-101 (5.0V | 1.2A Output)

No.000000000

• Introduction

This application note will provide the steps necessary to operate and evaluate ROHM's synchronous buck DC/DC converter using the BD9E151NUX evaluation boards. Component selection, board layout recommendations, operation procedures and application data is provided.

• Description

This evaluation board has been developed for ROHM's synchronous buck DC/DC converter customers evaluating BD9E151NUX. While accepting a power supply of 6.0-28.0V, an output of 1.0V to 23.0V can be produced. The IC has internal 80mOhm high-side MOSFET and a operation frequency fixed to 600 kHz. A fixed Soft Start circuit prevents in-rush current during startup along with UVLO (low voltage error prevention circuit) and TSD (thermal shutdown detection) protection circuits. An EN pin allows for simple ON/OFF control of the IC to reduce standby current consumption.

• Applications

Surveillance Camera Applications
OA Applications
12V, 24V Distributed Power Systems

• Evaluation Board Operating Limits and Absolute Maximum Ratings

Parameter		Symbol	Limit			Unit	Conditions
			MIN	TYP	MAX		
Supply Voltage							
	BD9E151NUX	V _{CC}	6.0	-	28.0	V	
Output Voltage / Current							
	BD9E151NUX	V _{OUT}	1.0 ^(*2)	-	VINx0.7 or VIN-5	V	* Set by R1 and R2
		I _{OUT}	-	-	1.2	A	

(*)Restricted by minimum on pulse typ. 100nsec

• Evaluation Board

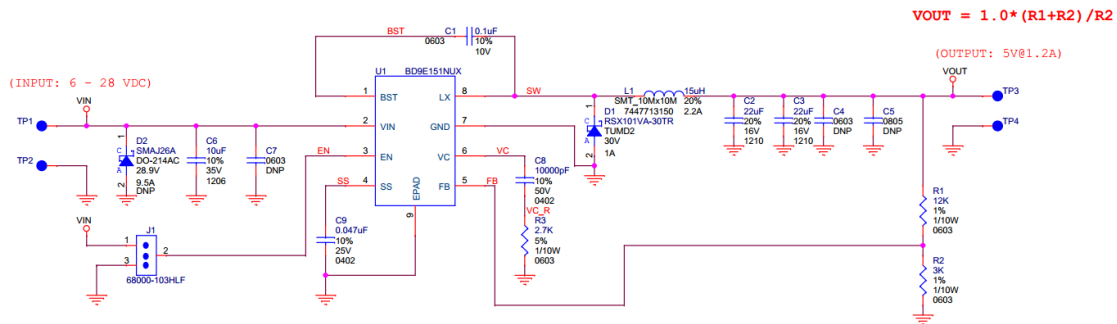
Below is evaluation board with the BD9E151NUX.



Fig 1: BD9E151NUX Evaluation Board

Evaluation Board Schematic

Below is evaluation board schematic for BD9E151NUX.



BD9E151NUX-E2EVK-101 Jumper Positions		
Reference Designator	Position	Description
J1	2 - 1	Enable U1
	2 - 3	Disable U1

Note:
1. $1V \leq V_{OUT} \leq 0.7 \cdot V_{IN}$ Or $V_{IN} \leq 5$

Fig 2: BD9E151NUX Evaluation Board Schematic

Evaluation Board I/O

Below is reference application circuit that shows the inputs (V_{IN} , EN) and the output (V_{OUT}).

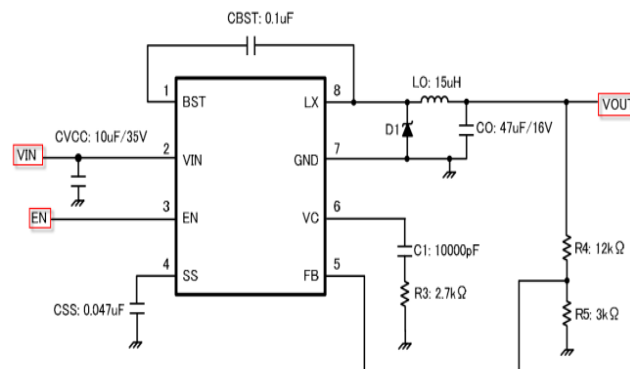


Fig 3: BD9E151NUX Evaluation Board I/O

Evaluation Board Operation Procedures

Below is the procedure to operate the evaluation board.

1. Connect power supply's GND terminal to GND test point TP2 on the evaluation board.
2. Connect power supply's V_{CC} terminal to V_{IN} test point TP1 on the evaluation board. This will provide V_{IN} to the IC U1. Please note that the V_{CC} should be in range of 6V to 28V.
3. Check if shunt jumper of J1 is at position ON (Pin2 connect to Pin1, EN pin of IC U1 is pulled high).
4. Connect electronic load to TP3 and TP4. Do not turn on load.
5. Turn on power supply. The output voltage V_{OUT} (+5V) can be measured at the test point TP3. Now turn on the load. The load can be increased up to 1.2A MAX.

Notes:

The board does not support hot plugging protection. Please do not hot plug power supply.

• **Reference Application Data for BD9E151NUX-E2EVK-101**

Following graphs show quiescent current, efficiency, load response, output voltage ripple response of the BD9E151NUX evaluation board.

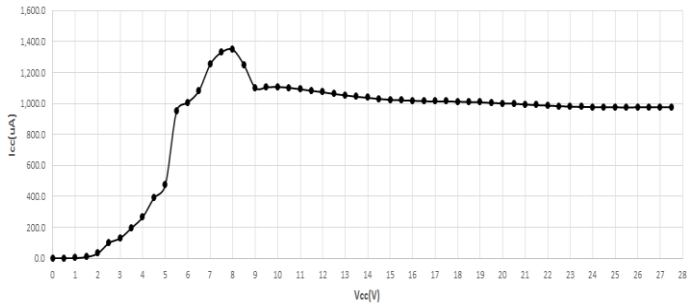


Fig 4: Circuit Current vs. Power supply Voltage Characteristics ($V_{IN} = 0-28V$, Temp=25°C)

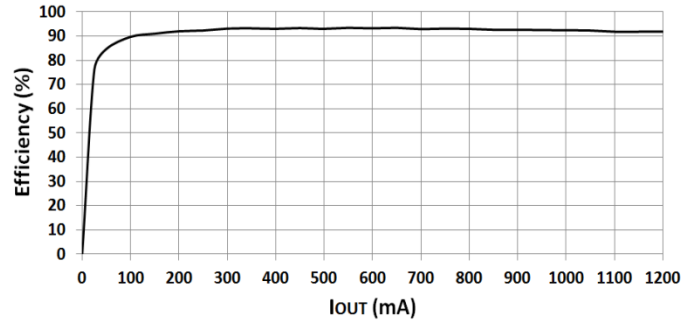


Fig 5: Electric Power Conversion Rate ($V_{in}=12V$, $V_{OUT}=5V$)

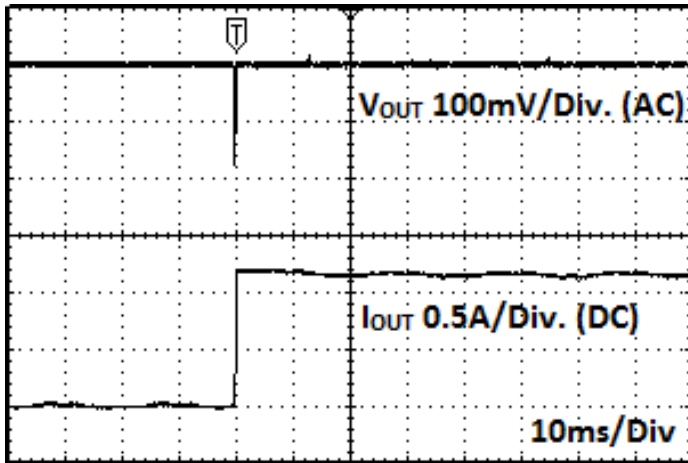


Fig 6: Load Response Characteristics ($V_{IN}=12V$, $V_{OUT}=5V$, $I_{OUT}=0A \rightarrow 1.2A$)

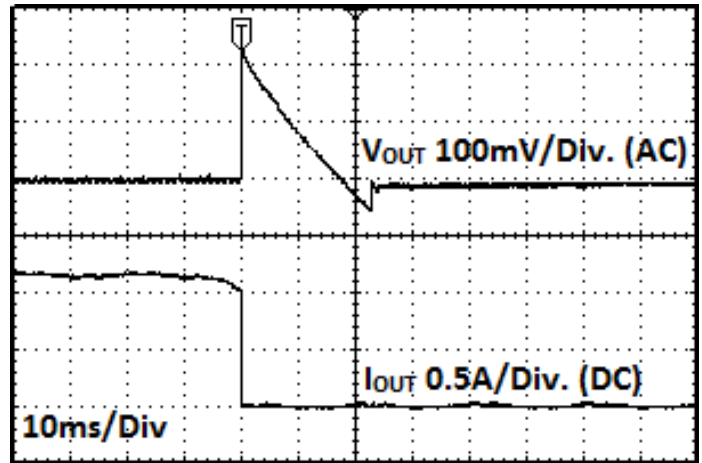


Fig 7: Load Response Characteristics ($V_{IN}=12V$, $V_{OUT}=5V$, $I_{OUT}=1.2A \rightarrow 0A$)

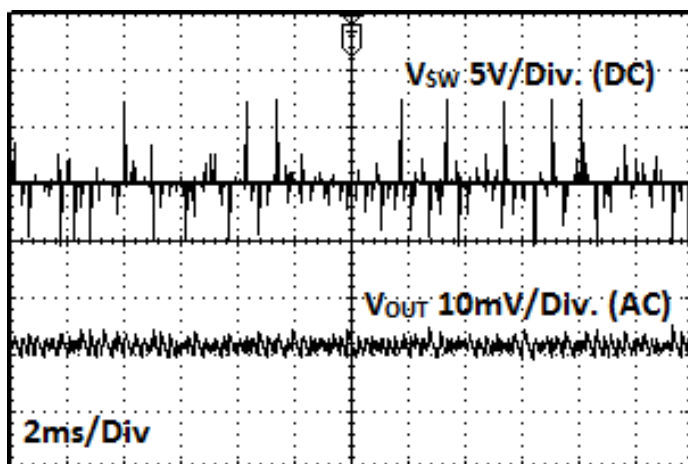


Fig 8: Output Voltage Ripple Response Characteristics ($V_{IN}=12V$, $V_{OUT}=5V$, $I_{OUT}=0A$)

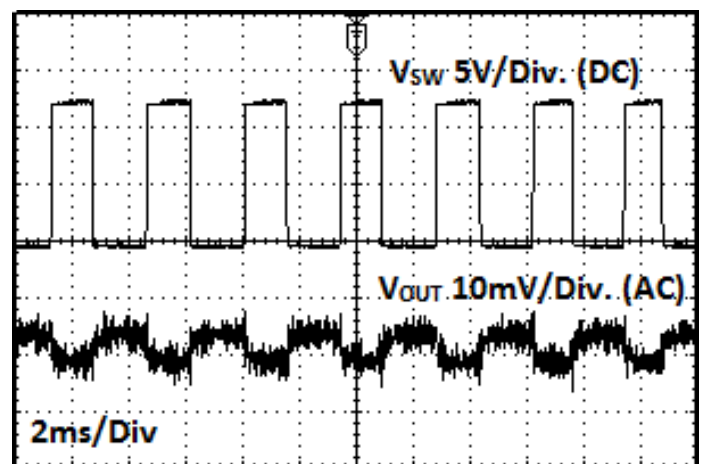


Fig 9: Output Voltage Ripple Response Characteristics ($V_{IN}=12V$, $V_{OUT}=5V$, $I_{OUT}=1.2A$)

• Evaluation Board Layout Guidelines

Below are the guidelines that have been followed and recommended for BD9E151NUX designs.

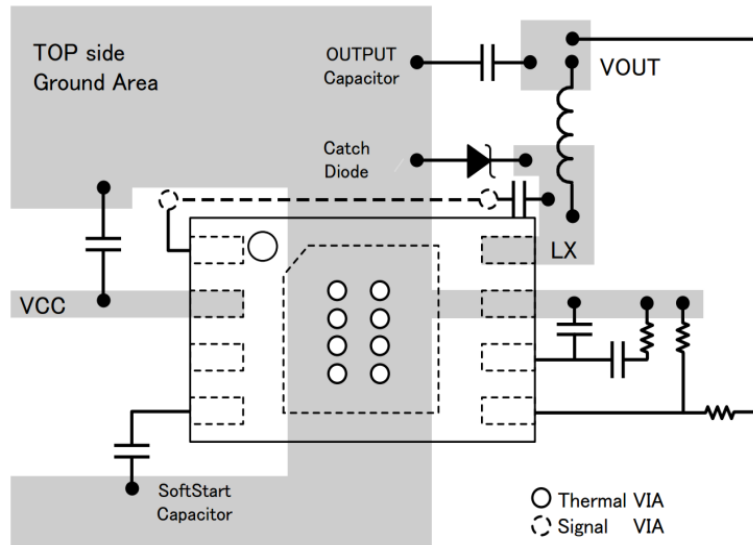


Fig 10: BD9E151NUX PCB Layout

Layout is a critical portion of good power supply design. There are several signals paths that conduct fast changing currents or voltages that can interact with stray inductance or parasitic capacitance to generate noise or degrade the power supplies performance. To help eliminate these problems, the V_{IN} pin should be bypassed to ground with a low ESR ceramic bypass capacitor with B dielectric. Care should be taken to minimize the loop area formed by the bypass capacitor connections, the V_{IN} pin, and the anode of the catch diode. See Fig 10 for a PCB layout example.

In the BD9E151NUX, since the LX connection is the switching node, the catch diode and output inductor should be located close to the LX pins, and the area of the PCB conductor minimized to prevent excessive capacitive coupling. And GND area should not be connected directly power GND, connected avoiding the high current switch paths. The additional external components can be placed approximately as shown.

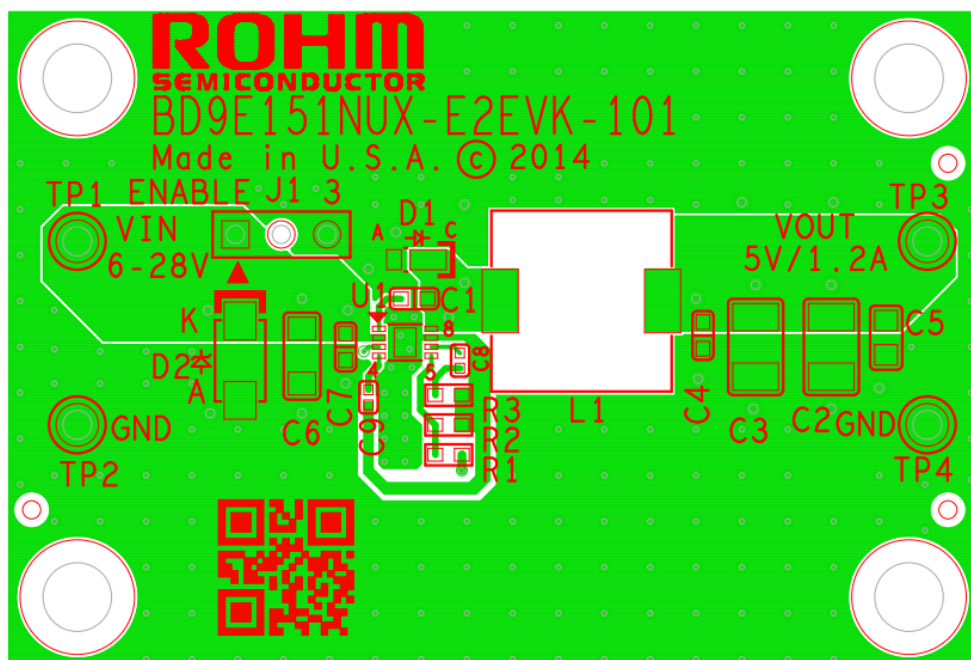


Fig 11: BD9E151NUX-E2EVK-101 Board PCB layout

• Calculation of Application Circuit Components

(1) Inductors

Something of the shield type that fulfills the current rating (Current value I_{pecac} below), with low DCR is recommended. Value of Inductance influences

Inductor Ripple Current and becomes the cause of Output Ripple.

In the same way as the formula below, this Ripple Current can be made small for as big as the L value of Coil or as high as the Switching Frequency.

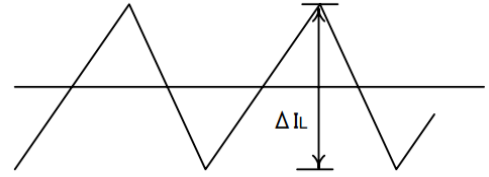


Fig 12: Inductor Current

$$I_{PEAK} = I_{OUT} + \frac{\Delta I_L}{2} \dots (1)$$

$$\Delta I_L = \frac{V_{IN} - V_{OUT}}{L} \times \frac{V_{OUT}}{V_{IN}} \times \frac{1}{f} \dots (2)$$

(ΔI_L : Output Ripple Current, V_{IN} : Input Voltage, V_{OUT} : Output Voltage, f : Switching Frequency)

For design value of Inductor Ripple Current, please carry out design tentatively with about 20%~50% of Maximum Input Current

(2) Output Capacitor

In order for capacitor to be used in output to reduce output ripple, Low ceramic capacitor of ESR is recommended.

Also, for capacitor rating, on top of putting into consideration DC Bias characteristics, please use something whose maximum rating has sufficient margin with respect to the Output Voltage. Output ripple voltage is looked for using the following formula. The actual value of the output capacitor is not critical, but some practical limits do exist. Consider the relationship between the crossover frequency of the design and LC corner frequency of the output filter. In general, it is desirable to keep the crossover frequency at less than 1/5 of the switching frequency. With high switching frequencies such as the 600kHz frequency of this design, internal circuit limitations of the BD9E151NUX limit the practical maximum crossover frequency to about 30kHz. In general, the crossover frequency should be higher than the corner frequency determined by the load impedance and the output capacitor. This limits the minimum capacitor value for the output filter to:

$$C_{OUT_min} = \frac{1}{2\pi \times R_L \times f_{c_max}} \dots (3)$$

Where: R_L is the output load resistance and f_{c_max} is the maximum crossover frequency. The output ripple voltage can be estimated by:

$$V_{PP} = \Delta I_L \times \frac{1}{2\pi \times f \times C_{OUT}} + \Delta I_L \times R_{ESR} \dots (4)$$

Please design in a way that it is held within Capacity Ripple Voltage.

In the BD9E151NUX, it is recommended a ceramic capacitor more than 10μF.

(3) Output Voltage Setting

ERROR AMP internal Standard Voltage is 1.0V. Output Voltage is determined as seen in (5) formula

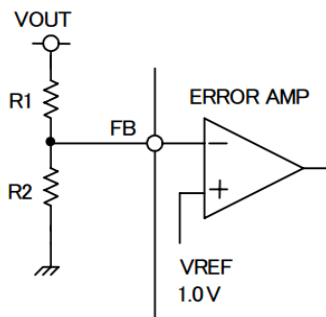


Fig 13: Output Voltage Setting

$$V_{OUT} = \frac{R1 + R2}{R2} \dots (5)$$

(4) Bootstrap Capacitor

Please connect from 0.047μF to 0.47μF (Laminate Ceramic Capacitor) between BST Pin and LX Pin.

(5) Soft Start Function

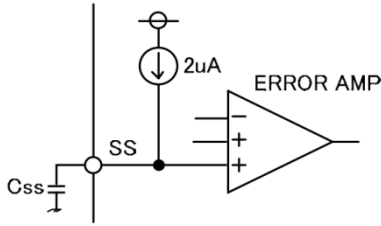


Fig 14: Soft Start Time Setting

It is highly recommended to program the soft start time externally to prevent high inrush current because no soft start time is implemented internally. A capacitor (C_{SS}) connected between the SS pin and ground implements a soft start time. The BD9E151NXX has an internal pull-up current source of 2uA that charges the external soft start capacitor. The equation for the soft start time (10% to 90%) is shown in below Equation. The I_{SS} current is 2uA.

$$T_{SS} = \frac{C_{SS} \times 0.1}{I_{SS}} \dots (6)$$

(6) Catch Diode

The BD9E151NXX is designed to operate using an external catch diode between LX and GND. The selected diode must meet the absolute maximum ratings for the application: Reverse voltage must be higher than the maximum voltage at the LX pin, which is $V_{INMAX} + 0.5$ V. Peak current must be greater than $I_{OUTMAX} + \Delta I_L$ plus on half the peak to peak inductor current. Forward voltage drop should be small for higher efficiencies. It is important to note that the catch diode conduction time is typically longer than the high-side FET on time, so attention paid to diode parameters can make a marked improvement in overall efficiency. Additionally, check that the device chosen is capable of dissipating the power losses.

(7) Input Capacitor

The BD9E151NXX requires an input capacitor and depending on the application. Use low ESR capacitors for the best performance. Ceramic capacitors are preferred, but low-ESR electrolytic capacitors may also suffice. The typical recommended value for the decoupling capacitor is 10uF. Please place this capacitor as close to the V_{IN} pin. When using ceramic capacitors, make sure that they have enough capacitance to provide sufficient charge to prevent excessive voltage ripple at input. The input voltage ripple caused by capacitance can be estimated by:

$$\Delta V_{CC} = \frac{I_{OUT}}{f \times C_{VCC}} \times \frac{V_{OUT}}{V_{CC}} \times \left[1 - \frac{V_{OUT}}{V_{CC}} \right] \dots (7)$$

Since the input capacitor (C_{VIN}) absorbs the input switching current it requires an adequate ripple current rating. The RMS current in the input capacitor can be estimated by:

$$I_{CVCC} = I_{OUT} \times \sqrt{\frac{V_{OUT}}{V_{CC}} \times \left(1 - \frac{V_{OUT}}{V_{CC}} \right)} \dots (8)$$

The worst case condition occurs at $V_{IN} = 2V_{OUT}$, where

$$I_{CVCC_max} = \frac{I_{OUT}}{2} \dots (9)$$

(8) About Adjustment of DC/DC Comparator Frequency Characteristics

Role of Phase compensation element C1, C2, R3 (See Fig 3 Example of Reference Application Circuit)
Stability and Responsiveness of Loop are controlled through VC Pin which is the output of Error Amp.
The combination of zero and pole that determines Stability and Responsiveness is adjusted by the combination of resistor and capacitor that are connected in series to the VC Pin.
DC Gain of Voltage Return Loop can be calculated for using the following formula.

$$A_{dc} = R_i \times G_{CS} \times A_{EA} \times \frac{V_{FB}}{V_{out}} \dots (10)$$

Here, V_{FB} is Feedback Voltage (1.0V). A_{EA} is Voltage Gain of Error amplifier (typ : 60 dB),
 G_{CS} is the Trans-conductance of Current Detect (typ : 10A/V), and R_i is the Output Load Resistance value.

There are 2 important poles in the Control Loop of this DC/DC.
The first occurs with through the output resistance of Phase compensation Capacitor (C1) and Error amplifier.
The other one occurs with through the Output Capacitor and Load Resistor.
These poles appear in the frequency written below.

$$f_{p1} = \frac{G_{EA}}{2\pi \times C1 \times A_{EA}} \dots (11)$$

$$f_{p2} = \frac{1}{2\pi \times C_{OUT} \times R_1} \dots (12)$$

Here, G_{EA} is the trans-conductance of Error amplifier (typ : 250uA/V).

Here, in this Control Loop, one zero becomes important.

With the zero which occurs because of Phase compensation Capacitor C1 and Phase compensation Resistor R3, the Frequency below appears.

$$f_{z1} = \frac{1}{2\pi \times C1 \times R3} \dots (13)$$

Also, if Output Capacitor is big, and that ESR (R_{ESR}) is big, in this Control Loop, there are cases when it has an important, separate zero (ESR zero).

This ESR zero occurs due to ESR of Output Capacitor and Capacitance, and exists in the Frequency below.

$$f_{zESR} = \frac{1}{2\pi \times C_{OUT} \times R_{ESR}} \dots (14) \quad (\text{ESR zero})$$

In this case, the 3rd pole determined with the 2nd Phase compensation Capacitor (C2) and Phase Correction Resistor (R3) is used in order to correct the ESR zero results in Loop Gain.

This pole exists in the frequency shown below.

$$f_{p3} = \frac{1}{2\pi \times C2 \times R3} \dots (15) \quad (\text{pole that corrects ESR zero})$$

The target of Phase compensation design is to create a communication function in order to acquire necessary band and Phase margin.

Cross-over Frequency (band) at which Loop gain of Return Loop becomes "0" is important.

When Cross-over Frequency becomes low, Power supply Fluctuation Response, Load Response, etc worsens.

On the other hand, when Cross-over Frequency is too high, instability of the Loop can occur.

Tentatively, Cross-over Frequency is targeted to be made 1/20 or below of Switching Frequency. Selection method of Phase Compensation constant is shown below.

1. Phase Compensation Resistor (R_3) is selected in order to set to the desired Cross-over Frequency.

Calculation of RC is done using the formula below.

$$R3 = \frac{2\pi \times C_{OUT} \times f_c}{G_{EA} \times G_{CS}} \times \frac{V_{OUT}}{V_{FB}} \dots (16)$$

Here, f_c is the desired Cross-over Frequency. It is made about 1/20 and below of the Normal Switching Frequency (f_s).

2. Phase compensation Capacitor (C1) is selected in order to achieve the desired phase margin.

In an application that has a representative Inductance value (about several 10uH~22uH), by matching zero of compensation to 1/4 and below of the Cross-over Frequency, sufficient Phase margin can be acquired. C1 can be calculated using the following formula.

$$C1 > \frac{4}{2\pi \times R3 \times f_c} \dots (17)$$

R_c is Phase compensation Resistor.

3. Examination whether the second Phase compensation Capacitor C2 is necessary or not is done.

If the ESR zero of Output Capacitor exists in a place that is smaller than half of the Switching Frequency, a second Phase compensation Capacitor is necessary. In other words, it is the case wherein the formula below happens.

$$\frac{1}{2\pi \times C_{OUT} \times R_{ESR}} < \frac{f_s}{2} \dots (18)$$

In this case, add the second Phase compensation Capacitor C2, and match the frequency of the third pole to the Frequency f_{p3} of ESR zero.

C2 is looked for using the following formula.

$$C2 = \frac{C_{OUT} \times R_{ERS}}{R3} \dots (19)$$

Output Voltage Restriction

BD9E151NUX have a function of BSTUVLO to prevent malfunction at low voltage between BST and LX. Therefore OUTPUT voltage is restricted by BSTUVLO and Max Duty Cycle (min 85%).

① Restriction by BST-UVLO

When the voltage between BST and LX is lower than 2.5V, High-Side FET will be made turned off and the charge will provide from V_{IN} to BST directly to reset BSTUVLO (path①). The below formula is needed to be satisfied to reset BSTUVLO.

$$V_{IN} \geq V_{IN} + V_F + \text{BSTUVLO reset} \dots (20)$$

Here, BSTUVLO reset: BSTUVLO reset voltage, V_F : the diode forward bias voltage between V_{IN} and BST
Considering the fluctuation of BSTUVLO reset voltage and V_F , maximum voltage is more than 5V.

Therefore maximum output voltage is defined as $V_{IN} - 5V$.

② Restriction by Max Duty Cycle

Maximum output voltage is restricted by Max Duty Cycle (min 85%).

In this time it is needed to consider the effect of NchFET R_{on} , OUTPUT current and forward voltage of SBD. OUTPUT voltage can be calculated using the following formula.

$$V_{OUT_max} = (V_{IN} - R_{ON} \times I_{OUT}) \times 0.85 - V_F \times 0.15 \dots (21)$$

Considering the effect of catch diode type and the loss by inductor,

$V_{omax} = (V_{IN} - R_{on} \times I_{omax}) \times 0.85$ (casually formula)

Considering the negative voltage in the case of pulling diode current, maximum voltage is more than $V_{IN} \times 0.7$.

Therefore maximum output voltage is defined as $V_{IN} \times 0.7$.

Considering above restriction, adopt the lower output voltage as maximum voltage

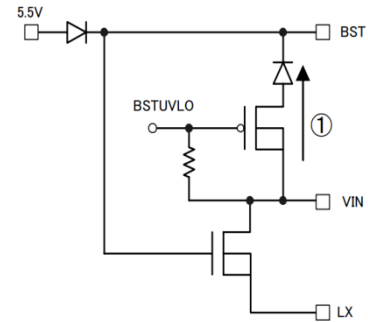


Fig 15: BST charge pass

- **Evaluation Board BOM**

Below is a table with the build of materials. Part numbers and supplier references are provided.

Item	Qty.	Ref	Description	Manufacturer	Part Number
1	1	C1	CAP CER 0.1UF 16V 10% X7R 0603	Murata	GRM188R71C104KA01D
2	2	C2,C3	CAP CER 22UF 16V 20% X7R 1210	Murata	GRM32ER71C226MEA8
3	1	C6	CAP CER 10UF 35V 10% X5R 1206	Murata	GRM31CR6YA106KA12L
4	1	C8	CAP CER 10000PF 50V 10% X7R 0402	Murata	GRM155R71H103KA88D
5	1	C9	CAP CER 0.047UF 25V 10% X7R 0402	Murata	GRM155R71E473KA88D
6	1	D1	DIODE SCHOTTKY 30V 1A 2TUMD	ROHM	RSX101VA-30TR
7	1	J1	CONN HEADER VERT .100 3POS 15AU	FCI	68000-103HLF
8	1	L1	INDUCTOR POWER 15UH 2.2A SMD	Würth Electronics	7447713150
9	1	R1	RES 12K OHM 1/10W 1% 0603 SMD	ROHM	MCR03ERTF1202
10	1	R2	RES 3K OHM 1/10W 1% 0603 SMD	ROHM	MCR03ERTF3001
11	1	R3	RES 2.7K OHM 1/10W 1% 0603 SMD	ROHM	MCR03ERTF2701
12	2	TP1,TP3	TEST POINT PC MULTI PURPOSE RED	Keystone Electronics	5010
13	2	TP2,TP4	TEST POINT PC MULTI PURPOSE BLK	Keystone Electronics	5011
14	1	U1	IC REG BUCK ADJ 1.2A 8VSON	ROHM	BD9E151NUX-TR
15	1		Shunt jumper for header J1 (item #8), CONN SHUNT 2POS GOLD W/HANDLE	TE Connectivity	881545-1

Notes

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